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SMR 1564 - 17

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**SPRING COLLEGE ON SCIENCE AT THE NANOSCALE**  
(24 May - 11 June 2004)

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**ELECTRONIC / THERMAL TRANSPORT - Part I**

**Philip KIM**  
Columbia University, Dept. of Physics, New York, U.S.A.

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*These are preliminary lecture notes, intended only for distribution to participants.*

# **Electric and Thermal Transport in Nanoscale Materials –Part I**

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**Philip Kim**

**Department of Physics  
Columbia University**

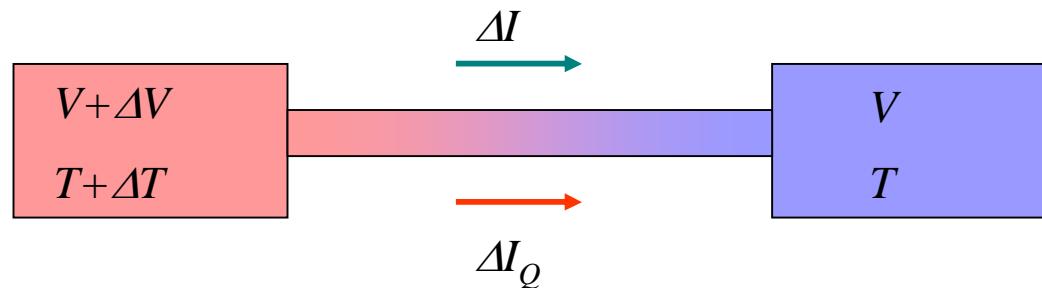


# Outline

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- Charge Transport and Energy Dissipation
- Mesoscopic Heat Transport Measurements
- Mesoscopic Thermoelectric Effects (Wed)
- Field Effect Transport in 2D Crystallites (Thr)

# Charge, Energy and Entropy Transport



Linear Response Regime

$$\Delta V = R \Delta I - S \Delta T$$

$$\Delta I_Q = \Pi \Delta I - K_{th} \Delta T$$

Onsager relation

$$\Pi = S T$$

$R$  : electric resistance (electron)

$K_{th}$  : thermal conductance (electron&phonon)

$S$  : Thermopower (electron+phonon)

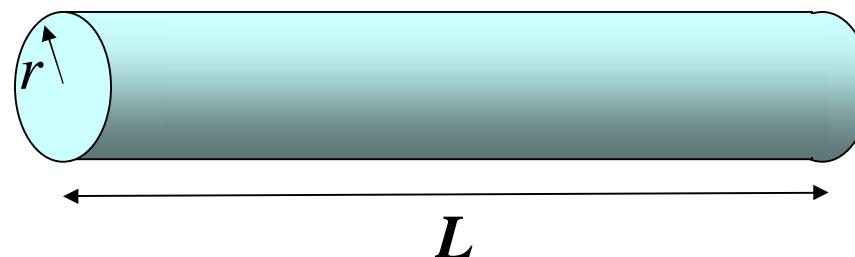
$\Pi$ : Peltier Coefficient

Wiedemann-Franz Law:

$$\frac{K_{th}}{1/R} = \frac{\pi^2}{3} \left( \frac{k_B}{e} \right)^2 T$$

# Classical Channel

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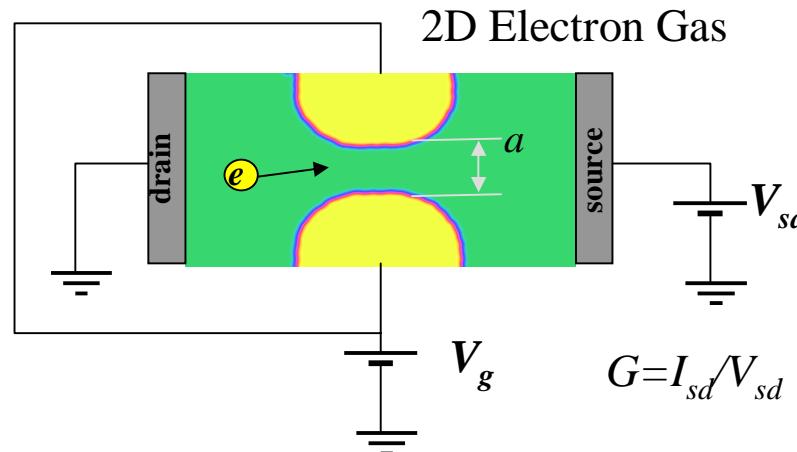
**Electric Conductance**

$$G = I/R = \sigma \pi r^2/L$$

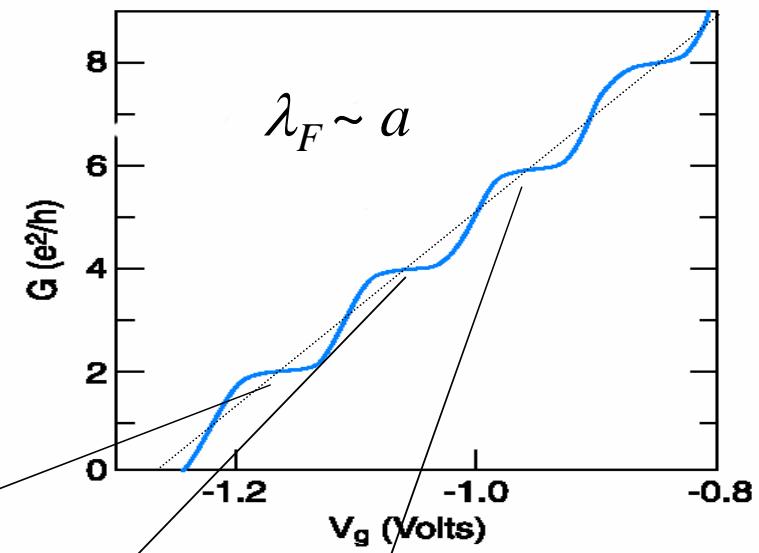
**Thermal Conductance**

$$K_{th} = \kappa \pi r^2/L$$

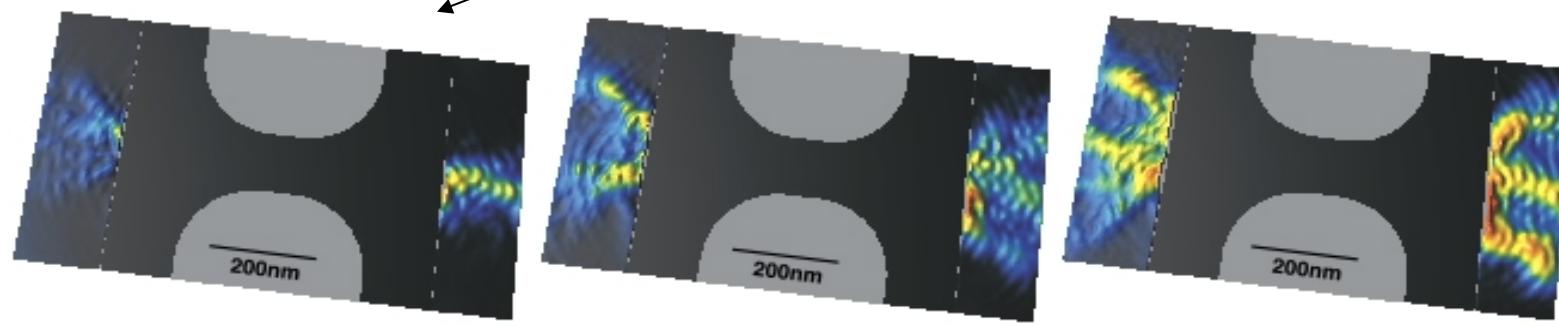
# Conductance Quantization in Quantum Point Contact



$$\text{Quantum Conductance: } g_0 = e^2/h$$

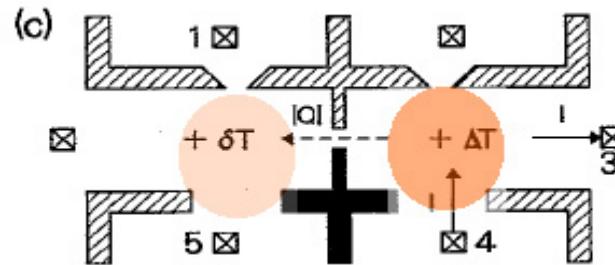


M. Topinka *et al*, *Science* (2000)

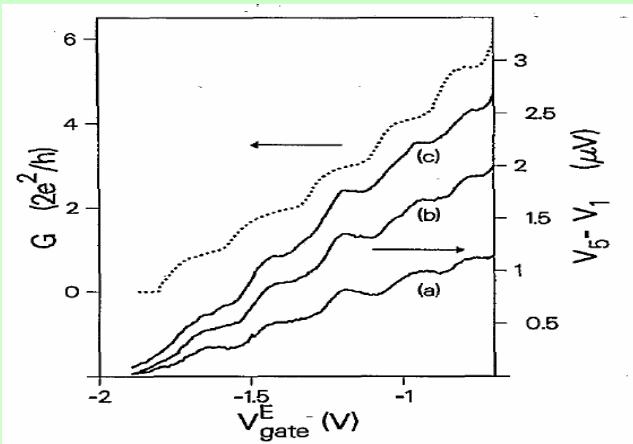


# Quantization of Thermal Properties in Mesoscopic Electron Systems

Quantum point contact



Electronic thermal conductance quantization  
(Molenkamp *et al.* PRL, 1991)



Quantum Thermal Conductance

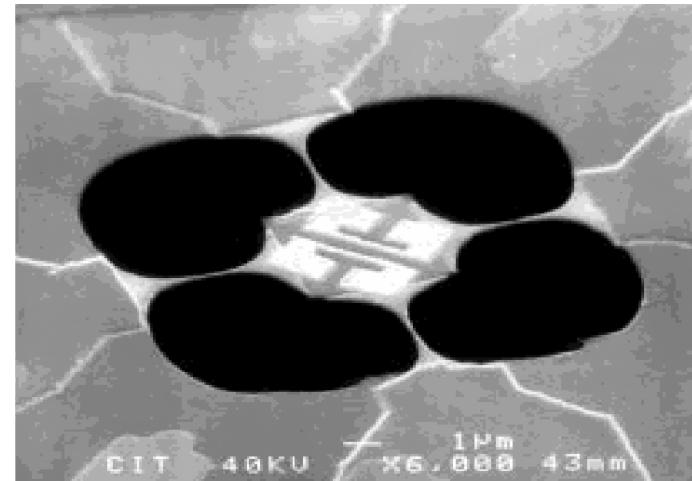
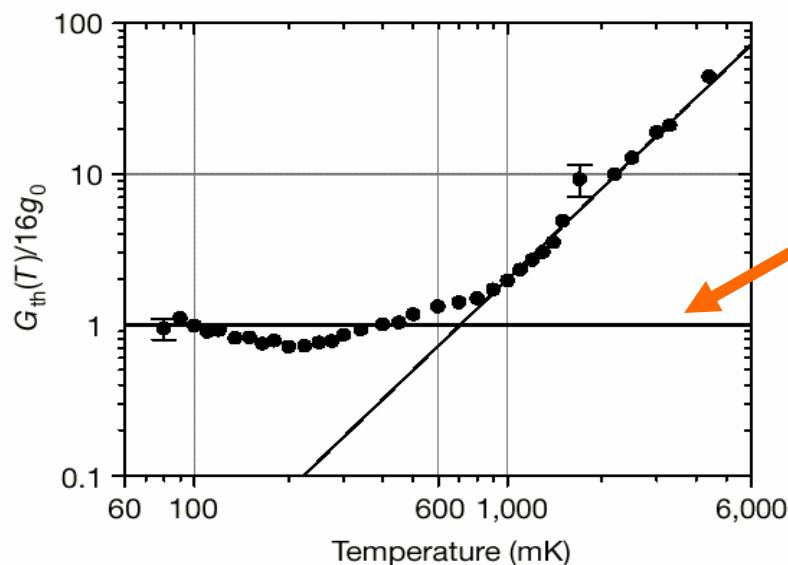
$$g_0^{th} = \pi^2 k_B^2 T / (3h)$$

Wiedemann-Franz Law:

$$\frac{g_0^{th}}{g_0^{el}} = \frac{\pi^2}{3} \left( \frac{k_B}{e} \right)^2 T$$

# Thermal Conductivity Quantization in Phonon System

Phonon thermal conductance quantization  
in Silicon Nitride Membrane Nanostructure  
(Schwab *et al.*, Nature, 1999)

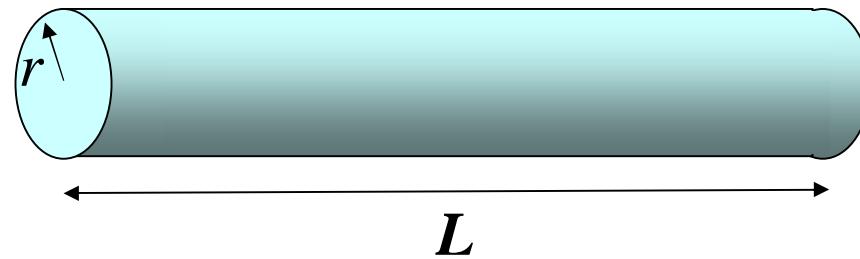


Quantum thermal  
conductance

$$g_0^{th} = \pi^2 k_B^2 T / (3h)$$

universal thermal quanta

# Quantum Transport Channel



$$r \sim \lambda_F, \lambda_{th}$$

**Electric Conductance**

$$G = \sigma \pi r^2 / L \quad \longrightarrow$$

$$G = N_{ch}^e g_0^e, \quad \# \text{ of channel}$$

$$g_0^e = e^2/h$$

**Thermal Conductance**

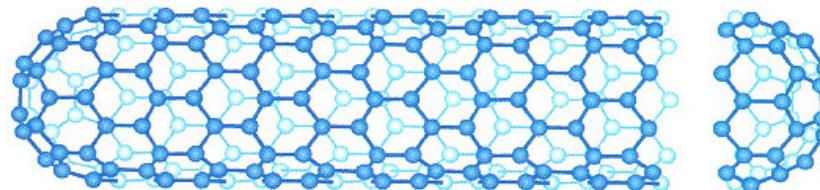
$$K_{th} = \kappa \pi r^2 / L \quad \longrightarrow$$

$$K_{th} = N_{ch}^{th} g_0^{th}, \quad g_0^{th} = \pi^2 k_B T / (3h)$$

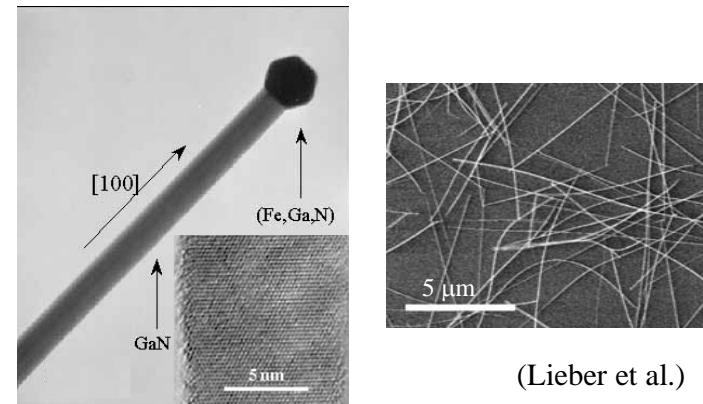
# Synthesized 1 Dimensional Nanoscale Materials

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Carbon Nanotubes

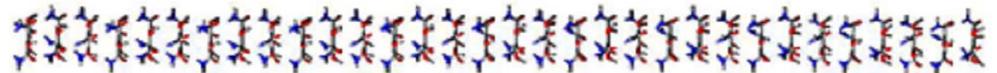


Semiconductor Nanowires

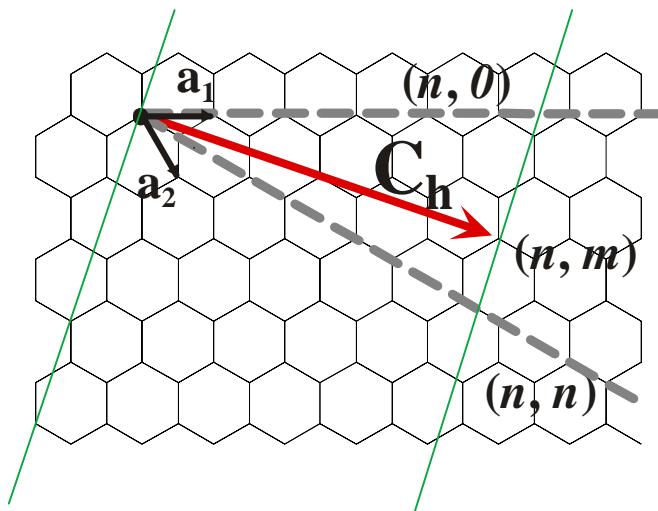


(Lieber et al.)

Organic Nanowires

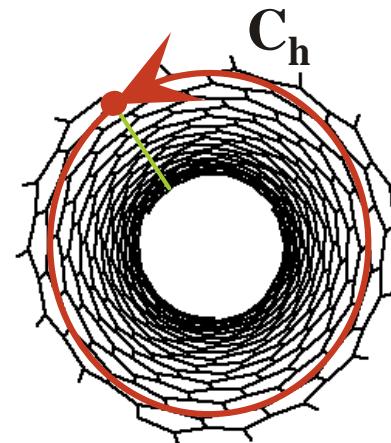


# Carbon Nanotube: Electronic Structure

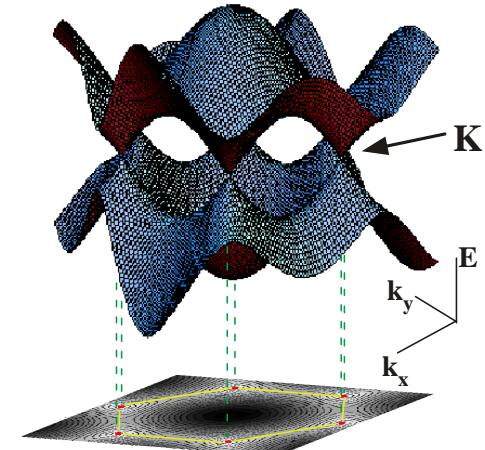


Rolling up graphene along  $C_h$  imposes a Periodic boundary condition :

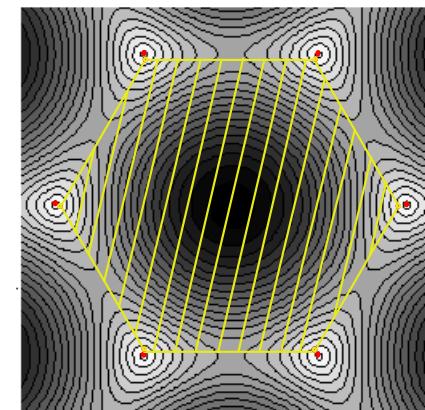
$$C_h \cdot k = 2\pi q$$



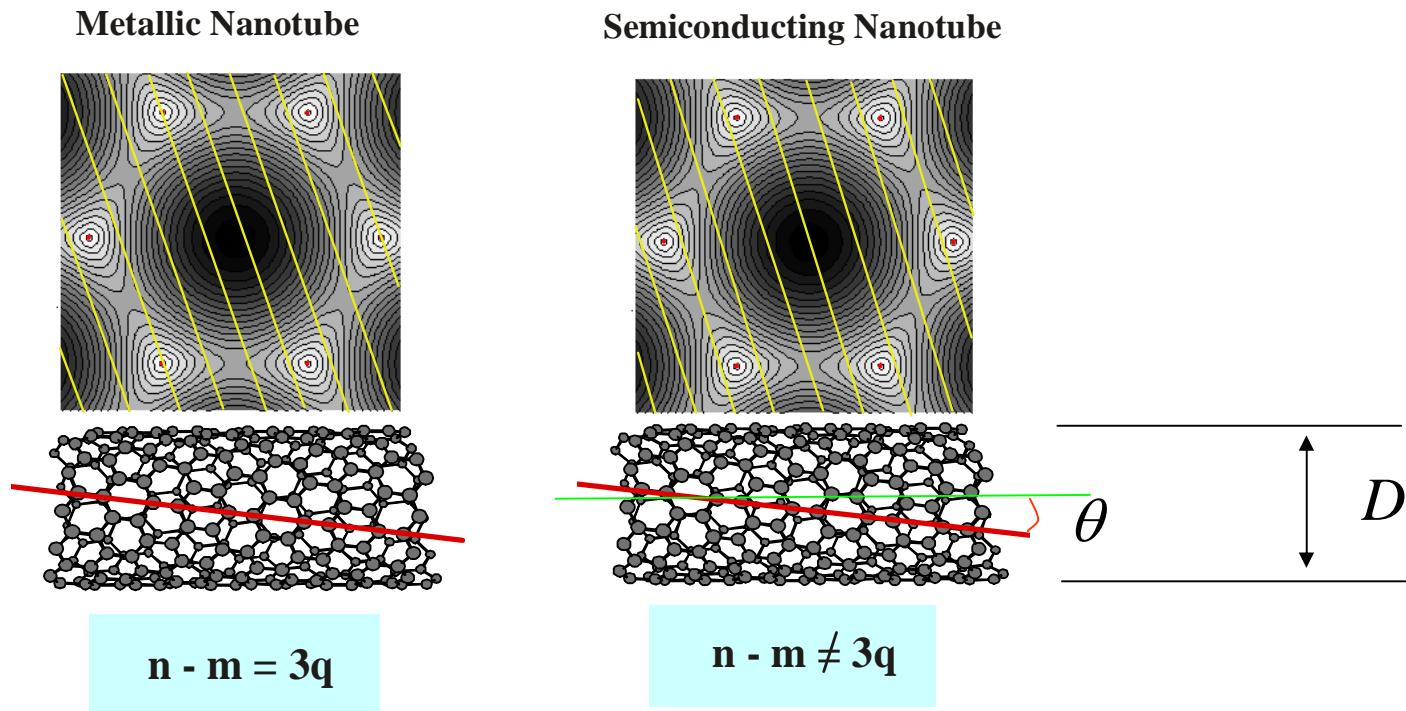
$\pi/\pi^*$  band of Graphene



set of allowed states



# Metallic and Semiconducting Nanotubes



$$D = |\mathbf{C}_h|/\pi = \sqrt{3}a_{cc}(m^2 + mn + n^2)^{1/2}/\pi$$

$$\theta = \tan^{-1} [(\mathbf{C}_h \times \mathbf{a}_1) \cdot \hat{\mathbf{z}} / \mathbf{C}_h \cdot \mathbf{a}_1] = \tan^{-1} [\sqrt{3}m/(m + 2n)] .$$

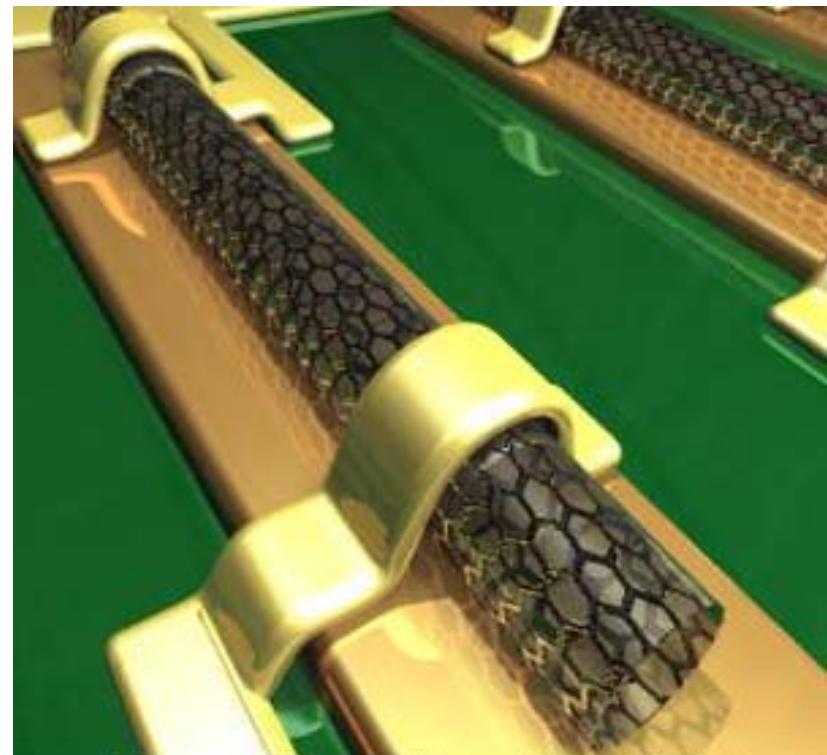
# Electrical Transport in Carbon Nanotube

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Metallic or semiconducting:  
depending on chirality&diameter

Exotic 1D electron system: Luttinger liquid?

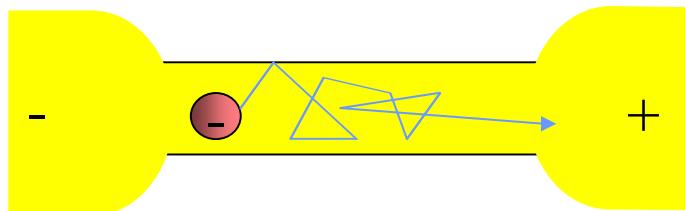
Ballistic electron transport in metallic tube:  
even at room temperature



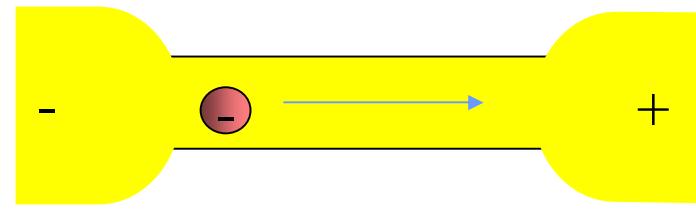
Artist's conception of a gated nanotube transistor logic circuit. Bachtold et al., *Science* **294** (2001) 1317.

# Ballistic Electron Transport

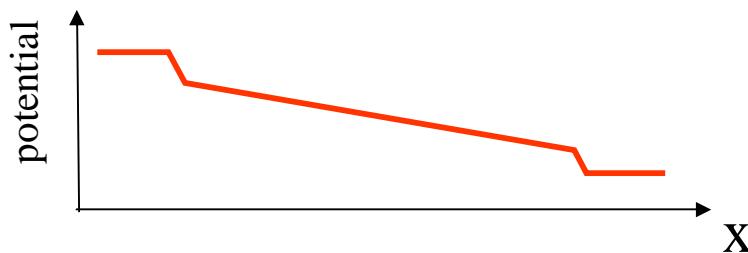
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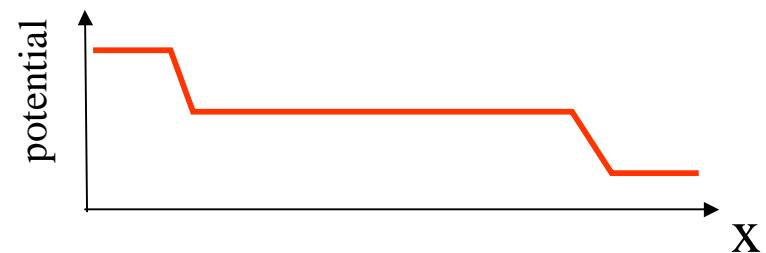
Diffusive



Ballistic



Ohmic Conductor



Quantum Transport

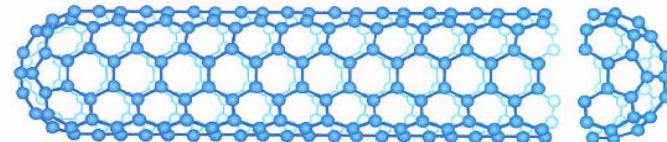
$$R = \rho L/A$$

$$R = h/2e^2N$$

# Charge Transport in Nanotubes

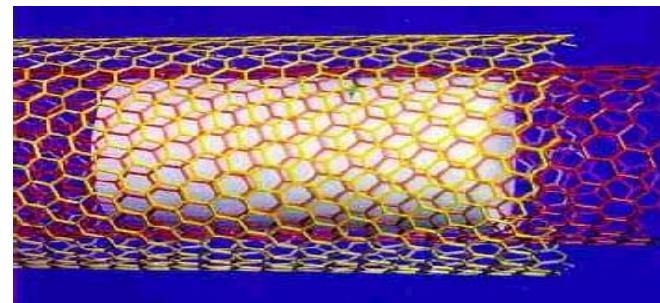
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Metallic Singlewall Nanotube :



Ballistic at low bias: (Schönenberger *et al.*, 1999, Bachtold *et al.*, 2000, Z. Yao *et al.*, 2000, Liang *et al.*, 2001)

Multiwall Nanotube :

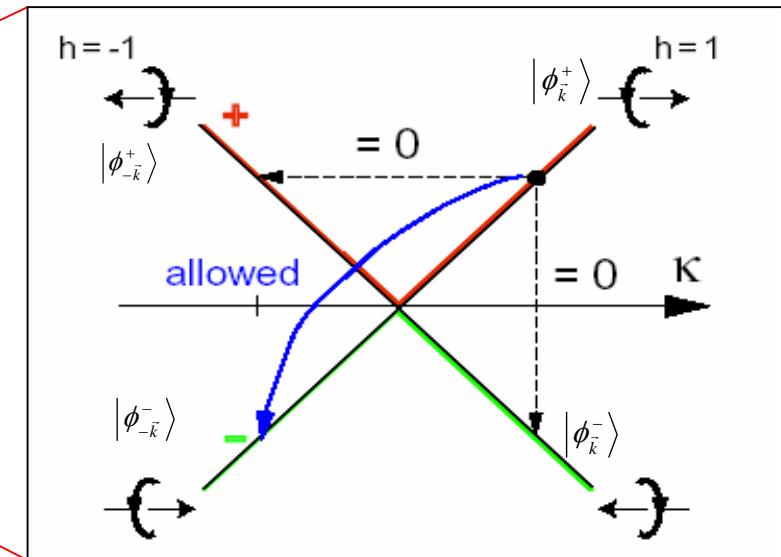
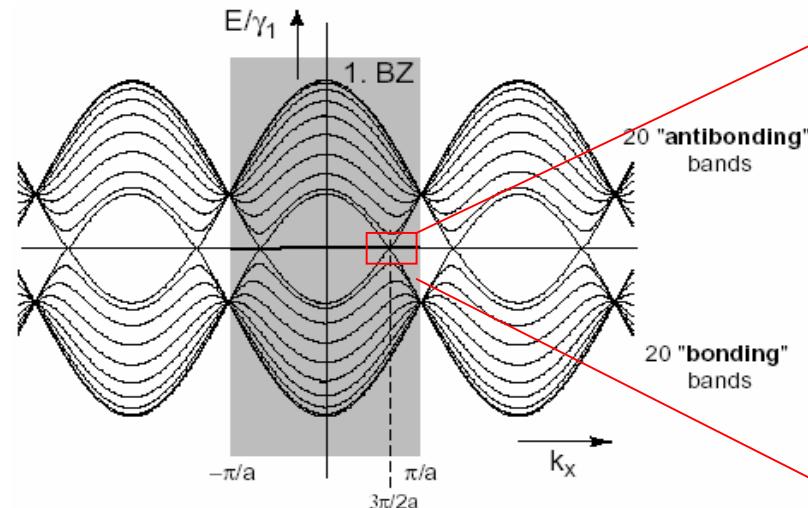


Ballistic (S. Frank *et al.*, 1998)

Diffusive (C. Schönenberger *et al.*, 1999, Bachtold *et al.*, 2000)

# Ballistic Electron Transport in Carbon Nanotube

Band Structure of Metallic Nanotube



$$H_{eff} \approx \hbar v_f \vec{\sigma} \cdot \vec{k}_{2D}$$

$\vec{\sigma}$ : Pauli matrices

$$\begin{aligned} |\langle \phi_k^+ | \langle \phi_k^+ \rangle|^2 &= 1 \\ |\langle \phi_k^- | \langle \phi_k^- \rangle|^2 &= 1 \\ |\langle \phi_k^+ | \langle \phi_{-\vec{k}}^- \rangle|^2 &= 1 \\ \langle \phi_k^+ | \langle \phi_{-\vec{k}}^+ \rangle &= 0 \\ \langle \phi_k^- | \langle \phi_{-\vec{k}}^- \rangle &= 0 \end{aligned}$$

Suppression of long wavelength **BACK** scattering

Ando et al., 1998

# Measurement of Electrical Field Distribution

## Electric Force Microscope (EFM)

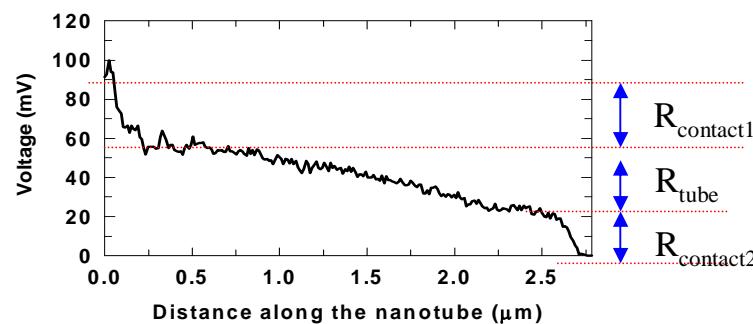
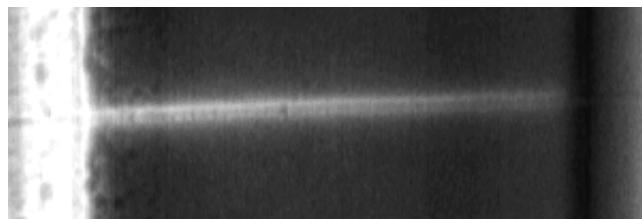


(Bachtold *et al.*, 2000)

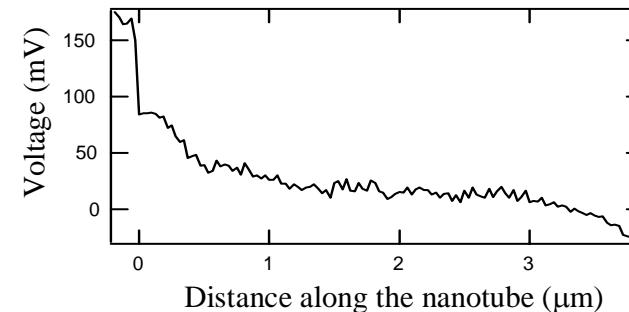
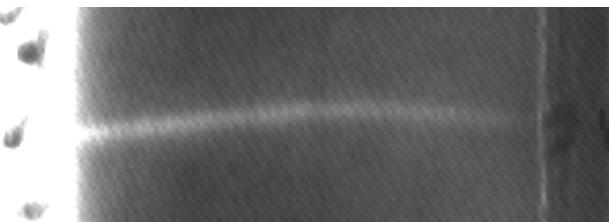
**AC EFM : probing local electric field**

$$F_{ac}(w) = (dC / dz)(V_{tip} + \phi)V_s(w)$$

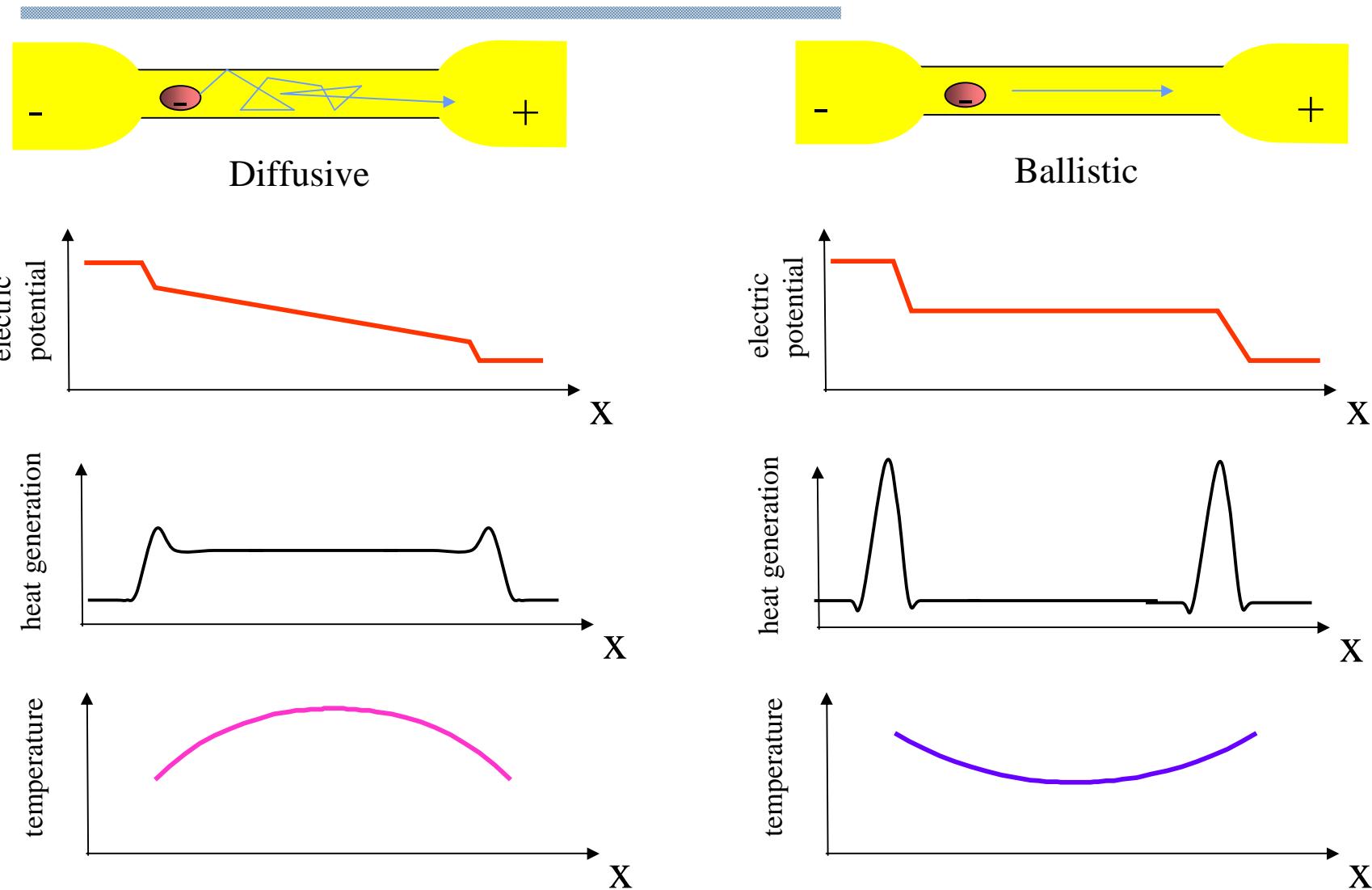
Multiwall Nanotube: diffusive



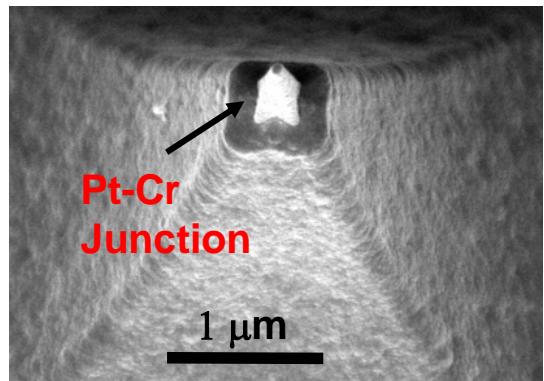
Singlewall Nanotube: ballistic



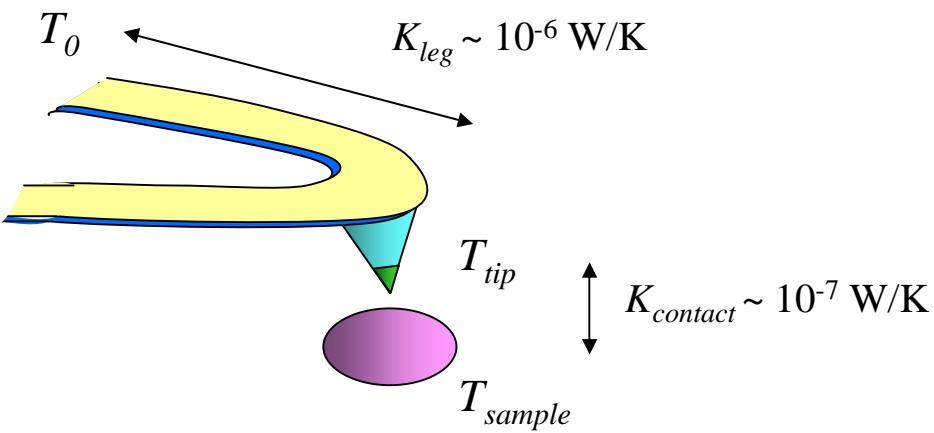
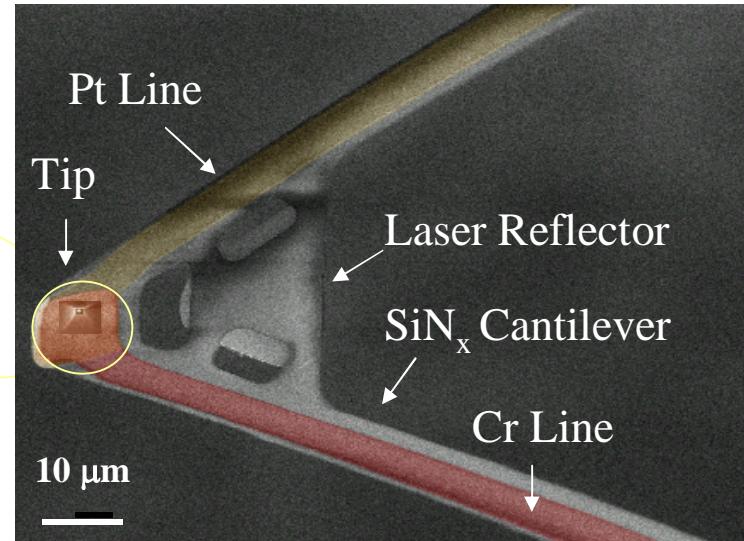
# Ballistic Electron Transport



# Local Temperature Probe



Probing local phonon temperature



Temperature reading :

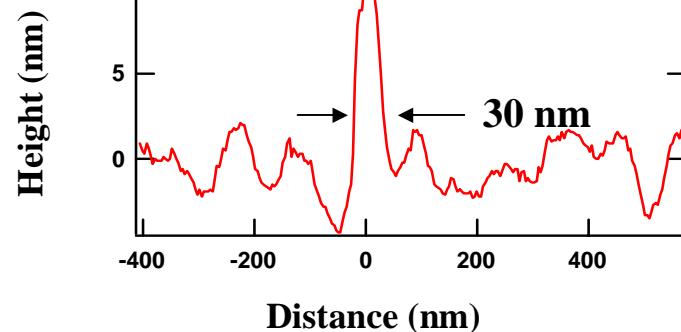
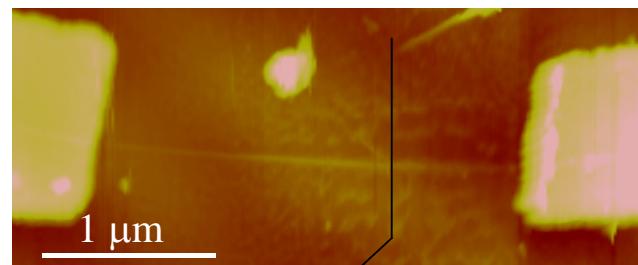
$$\Delta T_{sample} = \frac{K_{leg}}{K_{contact}} \Delta T_{tip}$$

t

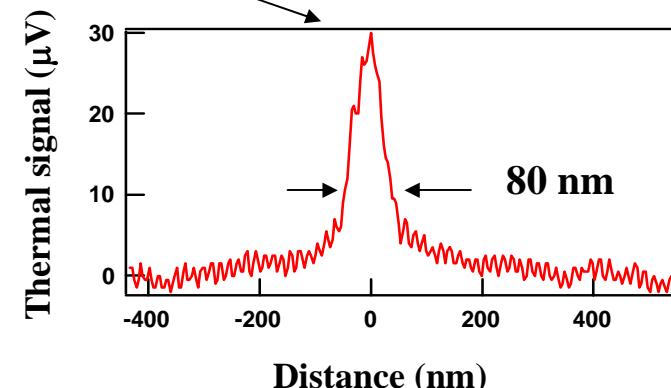
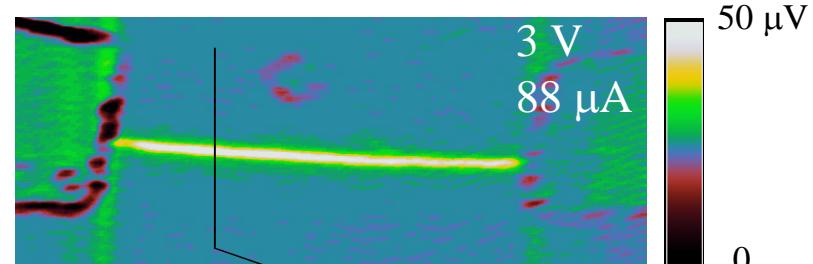
# Scanning Thermal Probe on Nanotube: Calibration

Multiwall Nanotube on 100 nm SiO/Si Substrate

Topography Image



Thermal Image



Seebeck coefficient of probe : 13.5  $\mu$ V/K

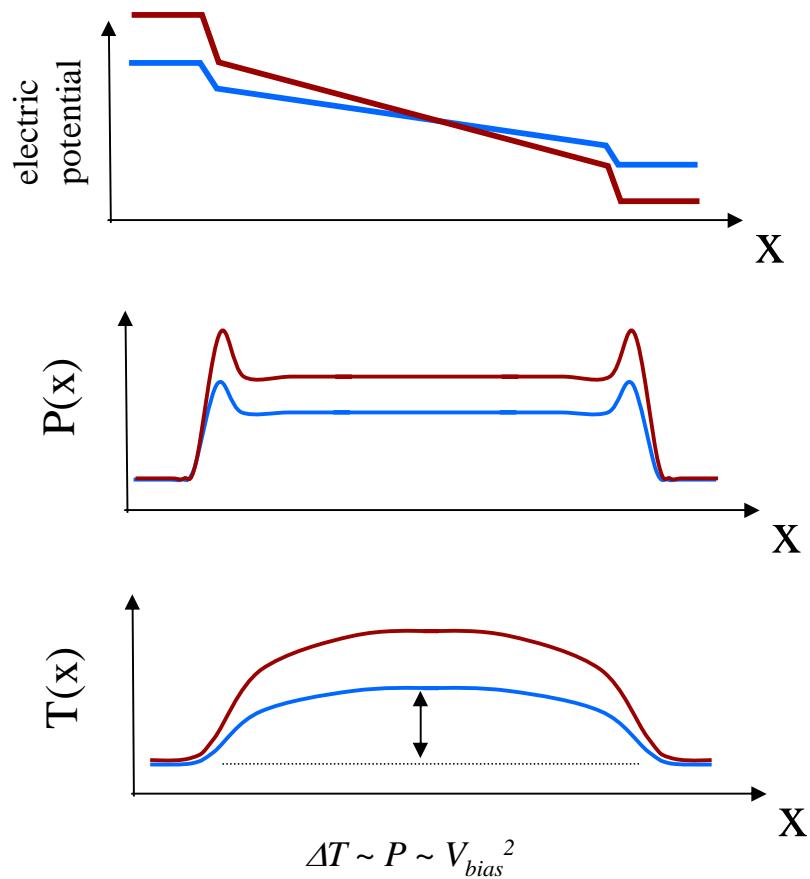
# Temperature Distribution of Diffusive Conductor

1d Diffusion Equation:

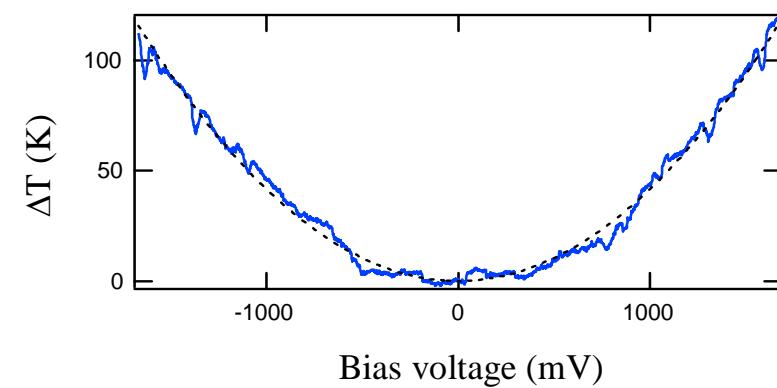
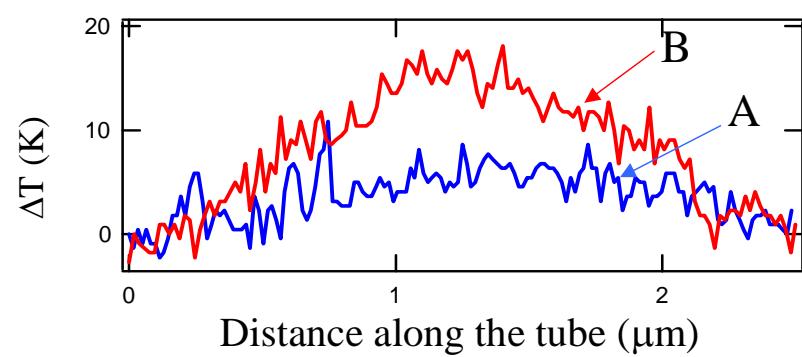
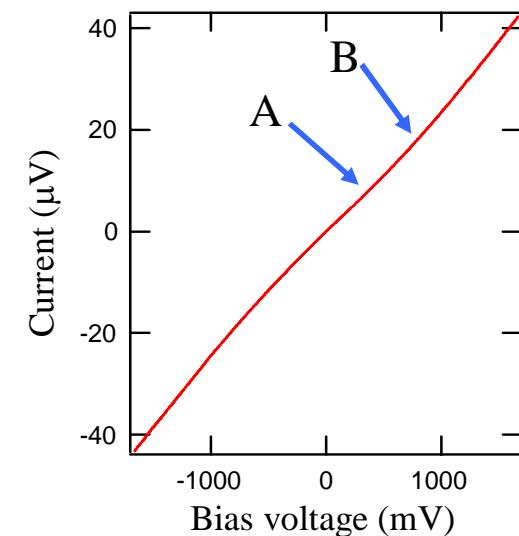
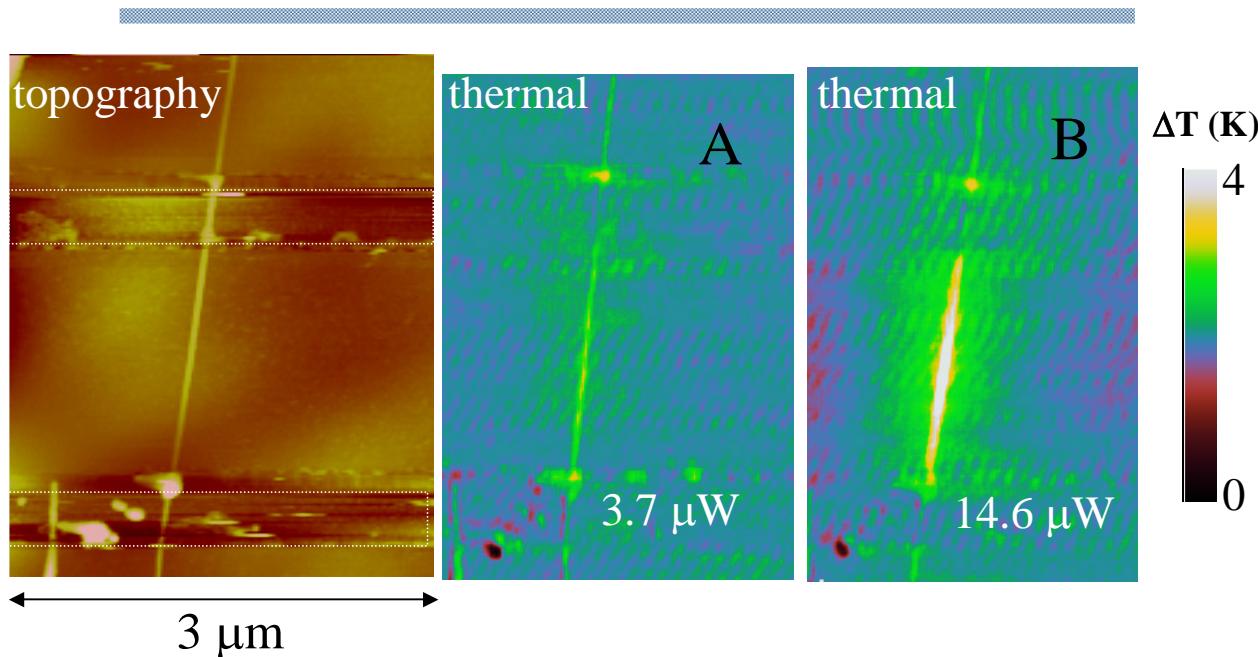
$$K \frac{d^2 T}{dx^2} = -P(x) + a(T(x) - T_s(x))$$

Thermal conductance  
Local power dissipation  
Coefficient of Substrate coupling  
Substrate temperature

Dissipative Transport

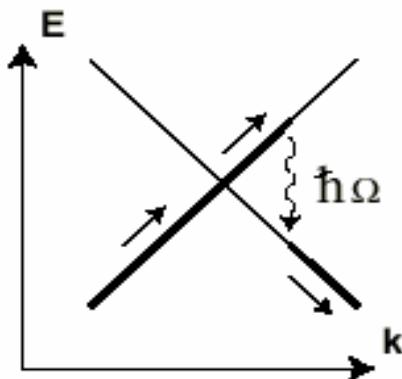


# Bulk Dissipation in Multiwall Nanotube



# Single Walled Nanotube: Energy Dissipation at High Field

- Optical Phonon Emission: from ballistic to diffusive

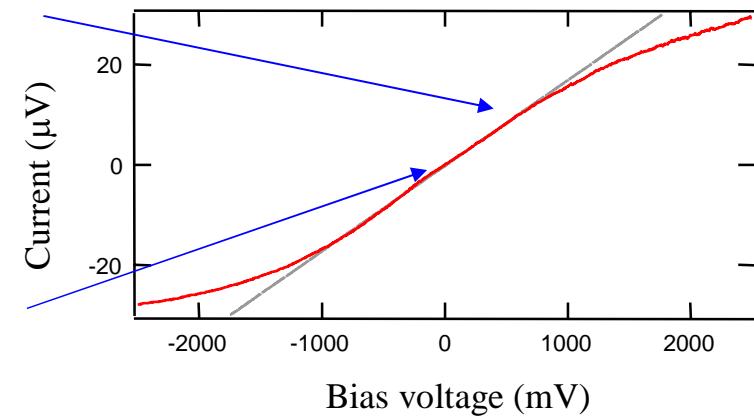


Onset of optical phonon  $\sim 150$  meV

Onset of optical phonon scattering

(Z. Yao *et al.*, 2000)

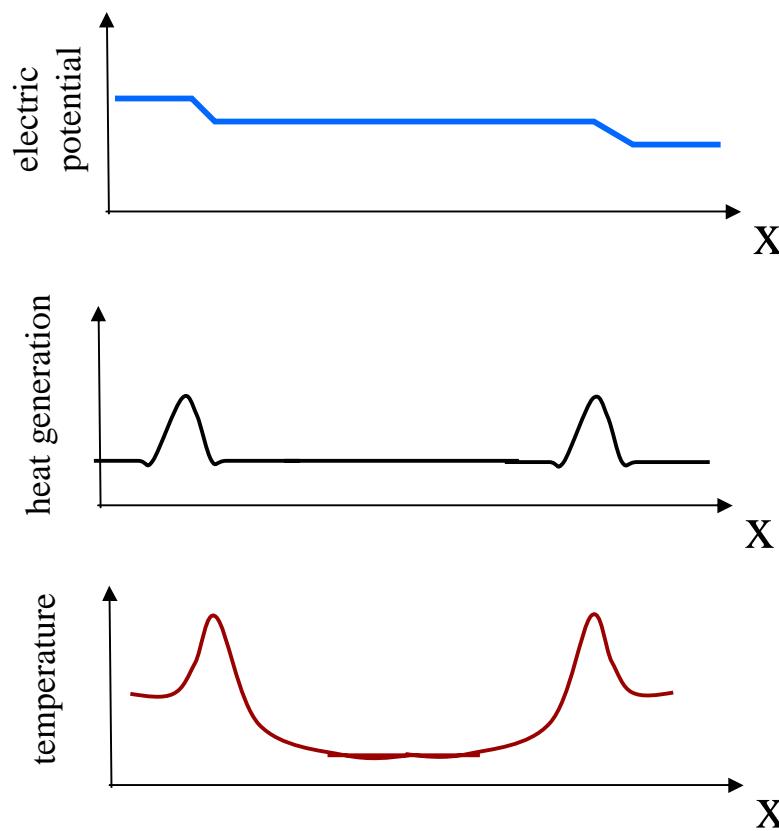
linear response regime, ballistic.



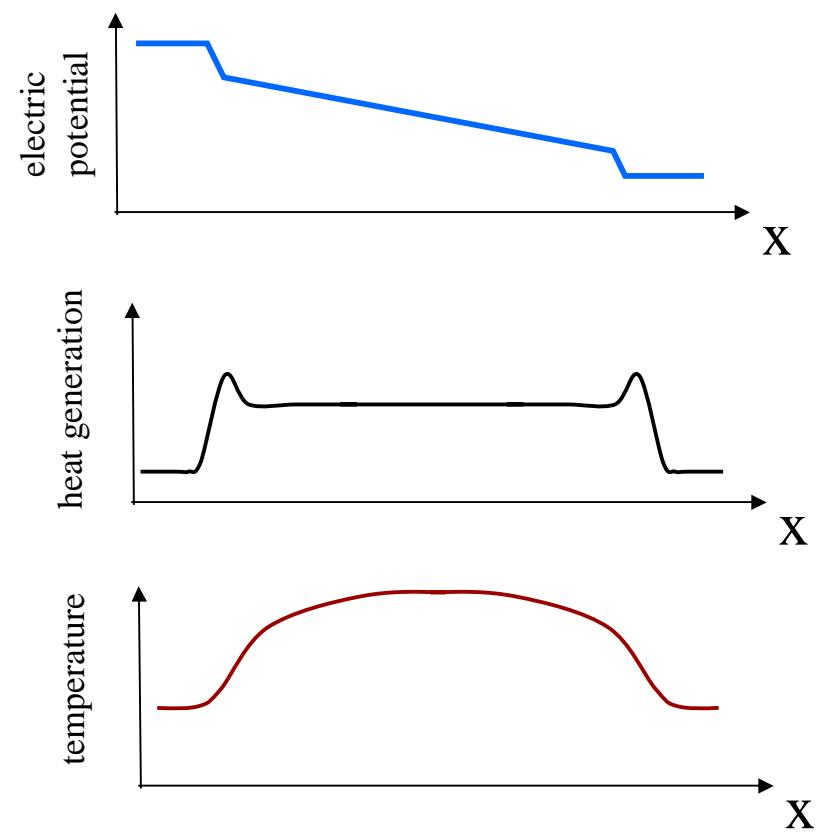
# Low Bias and High Bias Transport in SWNT

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**Low bias: ballistic**



**High bias: dissipative**



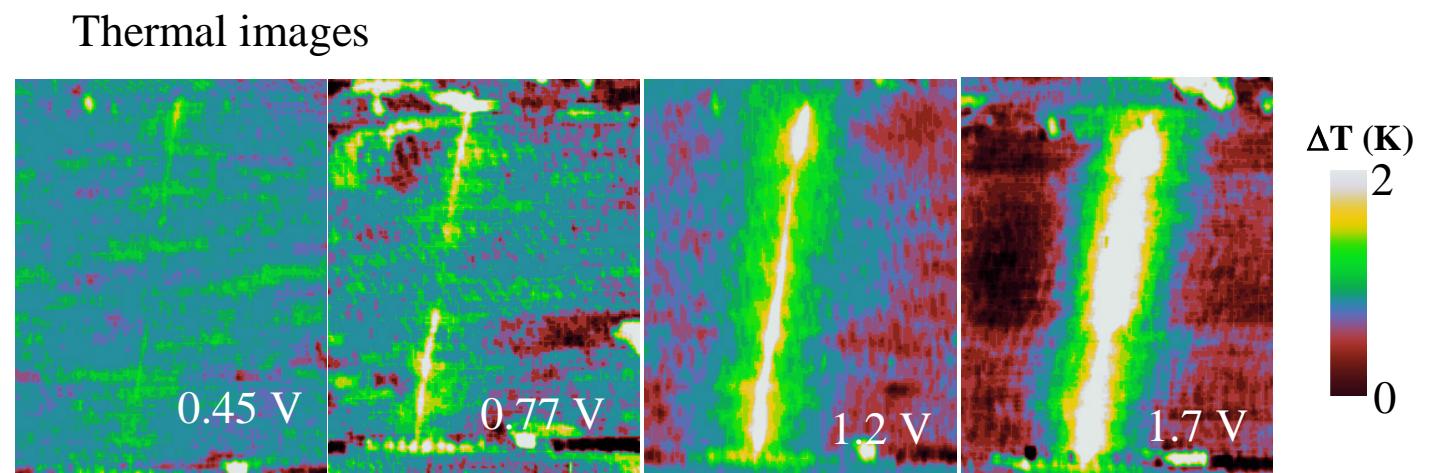
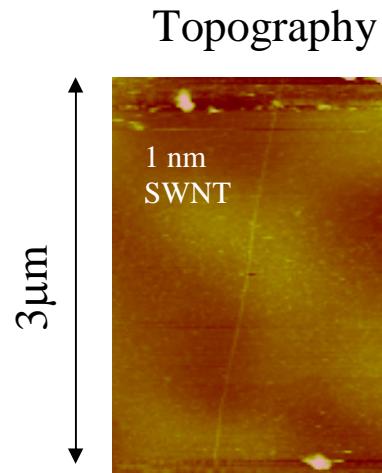
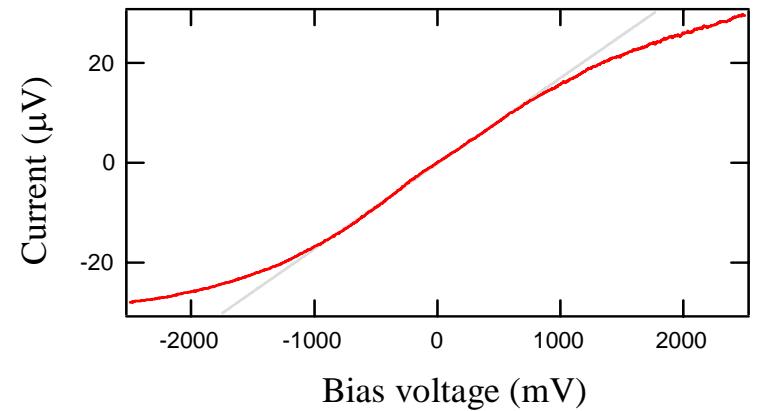
# Ballistic to Diffusive Transport

Low bias: ballistic

→ junction dissipation

High bias: diffusive

→ bulk dissipation



c

# **Measurement of Energy Flow**

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## **Thermal Conductivity**

$$K_{th} = \frac{dQ}{dT}$$

# Phonon Thermal Conductivity of Materials

Kinetic Theory

thermal conductivity

$$k = \frac{1}{3} C v_s l$$

specific heat

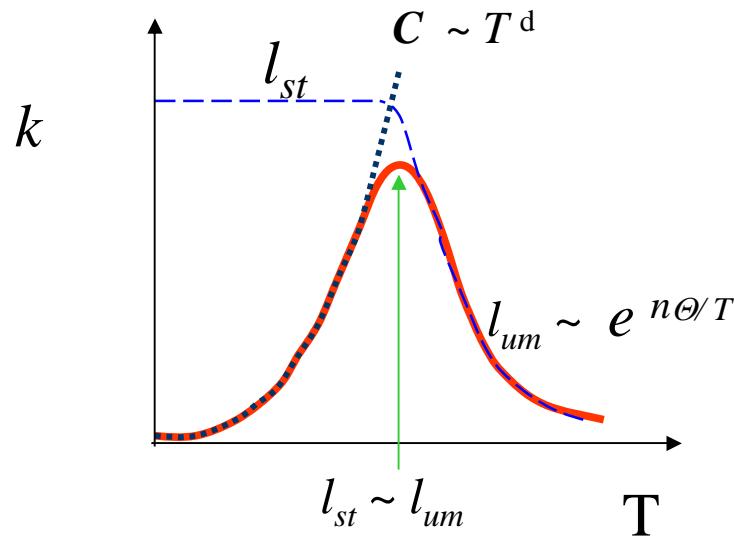
sound velocity

phonon mean free path

Specific heat :

If  $T \ll \Theta$ ,  $C \sim T^d$  (d:dimension)

If  $T > \Theta$ ,  $C \sim \text{constant}$



Mean free path:

$$\frac{1}{l} = \frac{1}{l_{st}} + \frac{1}{l_{um}}$$

Static scattering:  $l_{st} \sim \text{constant}$

Umklapp scattering:  $l_{um} \sim e^{+n\Theta/T}$